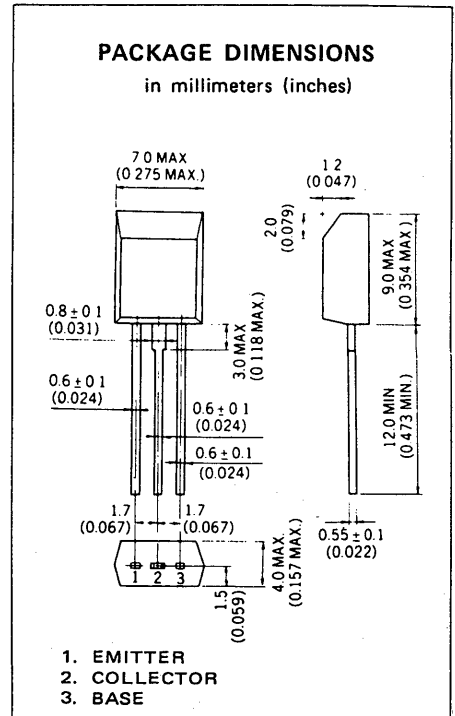


DESCRIPTION The 2SD471 is designed for use in driver and output stages of audio frequency amplifiers.

- FEATURES**
- High Total Power Dissipation:
1.0 W at 25 °C Ambient Temperature.
 - Complementary to the NEC 2SB564 PNP Transistor.

ABSOLUTE MAXIMUM RATINGS

Maximum Temperatures	
Storage Temperature -55 to +150 °C
Junction Temperature +150 °C Maximum
Maximum Power Dissipation (Ta = 25 °C)	
Total Power Dissipation 1.0 W
Thermal Resistance (Junction to Ambient) 125 °C/W
Maximum Voltages and Currents (Ta = 25 °C)	
V _{CBO} Collector to Base Voltage 30 V
V _{CEO} Collector to Emitter Voltage 25 V
V _{EBO} Emitter to Base Voltage 5.0 V
I _C Collector Current 1.0 A
I _B Base Current 0.1 A



ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

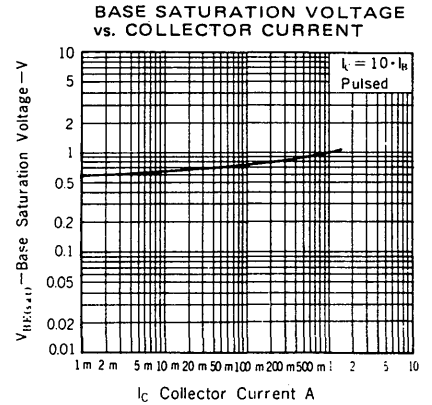
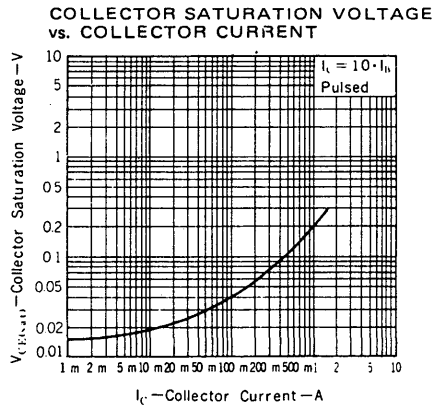
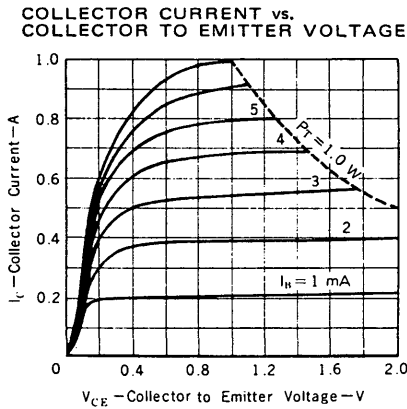
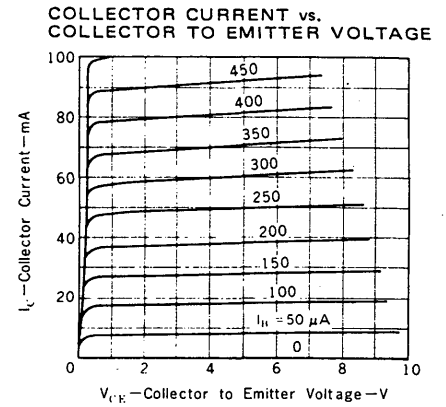
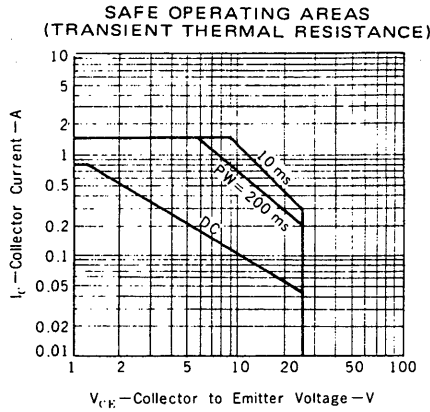
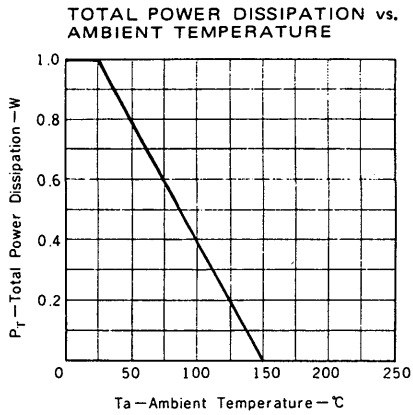
SYMBOL	CHARACTERISTIC	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
h _{FE1}	DC Current Gain	90	200	400		V _{CE} = 1.0 V, I _C = 0.1 A
h _{FE2}	DC Current Gain	50	140			V _{CE} = 1.0 V, I _C = 1.0 A
f _T	Gain Bandwidth Product		100		MHz	V _{CE} = 6.0 V, I _E = 10 mA
C _{ob}	Collector to Base Capacitance		22		pF	V _{CB} = 6.0 V, I _E = 0, f = 1.0 MHz
I _{CBO}	Collector Cutoff Current			100	nA	V _{CB} = 30 V, I _E = 0
I _{EBO}	Emitter Cutoff Current			100	nA	V _{EB} = 5.0 V, I _C = 0
V _{BE}	Base to Emitter Voltage	600	630	700	mV	V _{CE} = 6.0 V, I _C = 10 mA
V _{CE(sat)}	Collector Saturation Voltage		0.21	0.35	V	I _C = 1.0 A, I _B = 0.1 A
V _{BE(sat)}	Base Saturation Voltage		1.0	1.2	V	I _C = 1.0 A, I _B = 0.1 A

Classification of h_{FE1}

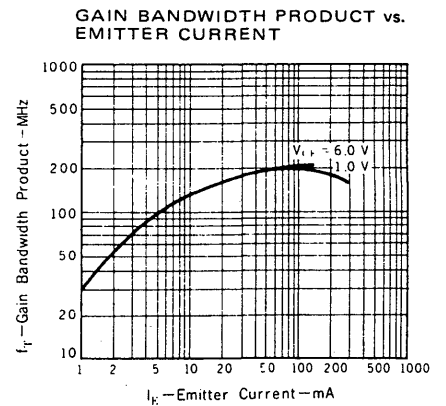
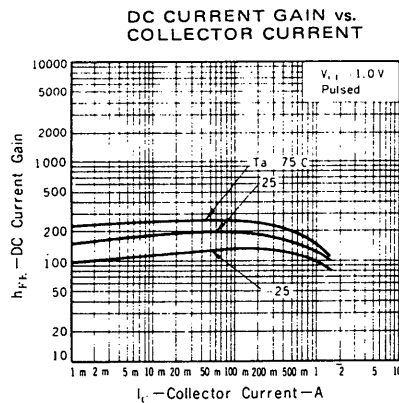
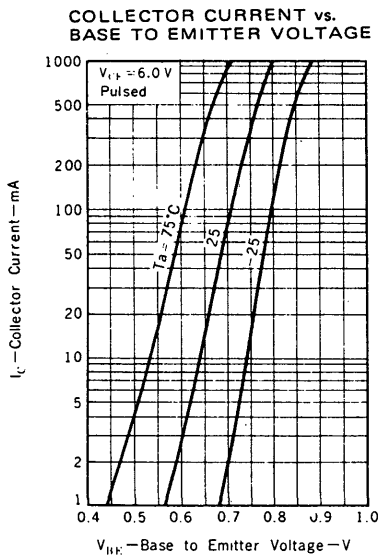
Rank	M	L	K
Range	90 - 180	135 - 270	200 - 400

h_{FE1} Test Conditions: V_{CE} = 1.0V, I_C = 0.1A

TYPICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless otherwise noted)



4-4



COLLECTOR TO BASE CAPACITANCE vs.
COLLECTOR TO BASE VOLTAGE

